Search Notes

| Des | 11:4- | Carch | DDs | Default | Diversio | Time Ctamp |
|----------|-------|---|---|---------------------|----------|------------------|
| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
| L1 | 332 | (438/430).CCLS. | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2005/09/26 16:54 |
| L2 | 1556 | (438/424).CCLS. | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2005/09/26 16:54 |
| L3 | 332 | (438/430):CCLS: | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2005/09/26 16:54 |
| L4 | 18 | L3 and rie and polysilicon and ((thermal adj oxide) or (lpteos)) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/09/26 16:54 |
| L5 | 18 | L3 and rie and polysilicon and ((thermal adj oxide) or (lpteos)) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/09/26 16:54 |
| L6 | 88 | trench and rie and polysilicon and ((thermal adj oxide) or (lpteos)) and hdp with cvd | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/09/26 16:54 |
| L7 | 1 | trench and rie and polysilicon and (Ipteos) and hdp with cvd | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/09/26 16:54 |
| L8 | 71 | trench and rie and polysilicon and (ozone with teos) and Ipcvd and nitride | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/09/26 16:55 |
| L9 | 36 | trench and rie and polysilicon and (ozone with teos) and hdp with cvd and nitride | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/09/26 16:55 |

| L10 | 14 | trench and rie and polysilicon and lpteos | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/09/26 16:55 |
|-----|------|---|---|----|-----|------------------|
| L11 | 79 | psg same usg and trench and sti and sidewall | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/09/26 16:55 |
| L12 | 0 | "LEE-JAE.in. " | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/09/26 17:00 |
| L13 | 0 | "LEE-JAE.in. " | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/09/26 17:01 |
| L14 | 4 | lee-jae.in. | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/09/26 17:01 |
| S1. | 1462 | (438/424):CCLS: | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2005/09/26 16:54 |
| S2 | 324 | (438/430).CCLS. | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2005/09/26 16:54 |
| S3. | 1 | S2 and rie and polysilicon and ((thermal adj oxide) or (lpteos)) and hdp with cvd | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/06 20:22 |
| S4 | 18 | S2 and rie and polysilicon and ((thermal adj oxide) or (lpteos)) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/09/26 16:54 |
| S5 | 1218 | trench and rie and polysilicon and ((thermal adj oxide) or (lpteos)) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/06 20:13 |

| S6 | 81 | trench and rie and polysilicon and ((thermal adj oxide) or (lpteos)) and hdp with cvd | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/09/26 16:54 |
|-----|-----|---|---|------|----|-----------------------|
| S7 | 1 | trench and rie and polysilicon and (Ipteos) and hdp with cvd | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR . | ON | 2005/09/26 16:54 |
| S8 | 1 | trench and rie and polysilicon and (Ip-teos) and hdp with cvd | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/06 20:14 |
| S9 | 1 | trench and rie and polysilicon and (Ipteos) and hdp with cvd | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/06 20:23 |
| S10 | | trench and rie and polysilicon and (thermal adj oxide) and hdp with cvd | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/06 20:23 |
| S11 | 80 | trench and rie and polysilicon and (thermal adj oxide) and hdp with cvd and nitride | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/06 20:23 |
| S12 | 123 | trench and rie and polysilicon and (teos) and hdp with cvd and nitride | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/06 20:23 |
| S13 | 33 | trench and rie and polysilicon and (ozone with teos) and hdp with cvd and nitride | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/09/26 16:55 |
| S14 | 66 | trench and rie and polysilicon and (ozone with teos) and lpcvd and nitride | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/09/26 16:55 • |
| S15 | 14 | trench and rie and polysilicon and lpteos | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/09/26 16:55 |

| S16 | . 112 | psg and usg and trench and sti | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/13 10:14 |
|-----|-------|---|---|-----|----|------------------|
| S17 | 78 | psg and usg and trench and sti and sidewall | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR- | ON | 2005/06/13 10:14 |
| S18 | | psg same usg and trench and sti and sidewall | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/09/26 16:55 |